Kingbright

5.0mm x 6.0mm FULL COLOR SURFACE MOUNT LED LAMP

ATTENTION
OBSERVE PRECAUTIONS
FOR HANDLING
ELECTROSTATIC
DISCHARGE
SENSITIVE
DEVICES

AAA5060SEEVGPBE HYPER ORANGE
GREEN
BLUE

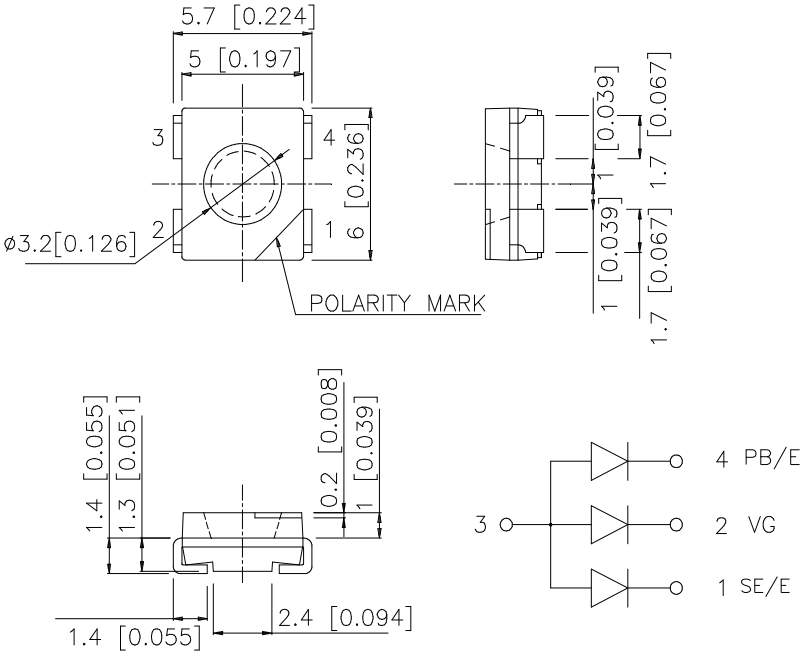
Features

- ●CHIPS CAN BE CONTROLLED SEPARATELY.
- ●SUITABLE FOR ALL SMT ASSEMBLY AND SOLDER PROCESS.
- ●AVAILABLE ON TAPE AND REEL.
- ●PACKAGE: 500PCS / REEL.
- ●RoHS COMPLIANT.

Description

The Hyper Orange source color devices are made with DH InGaAlP on GaAs substrate Light Emitting Diode.
The Green source color devices are made with InGaN on SiC Light Emitting Diode.
The Blue source color devices are made with InGaN on SiC Light Emitting Diode.
Static electricity and surge damage the LEDS.
It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs.
All devices, equipment and machinery must be electrically grounded.

Package Dimensions



Notes:
1. All dimensions are in millimeters (inches).
2. Tolerance is ±0.25(0.01") unless otherwise noted.
3. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Lens Type	Iv (mcd) @50mA* 30 mA		Viewing Angle
			Min.	Typ.	2 θ 1/2
AAA5060SEEVGPBE	HYPER ORANGE(InGaAIP)	WATER CLEAR	650	1000	100°
	GREEN (InGaN)		*180	*350	
	BLUE (InGaN)		*110	*250	

Notes:
1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.
2. * Luminous intensity with asterisk is measured at 30mA.

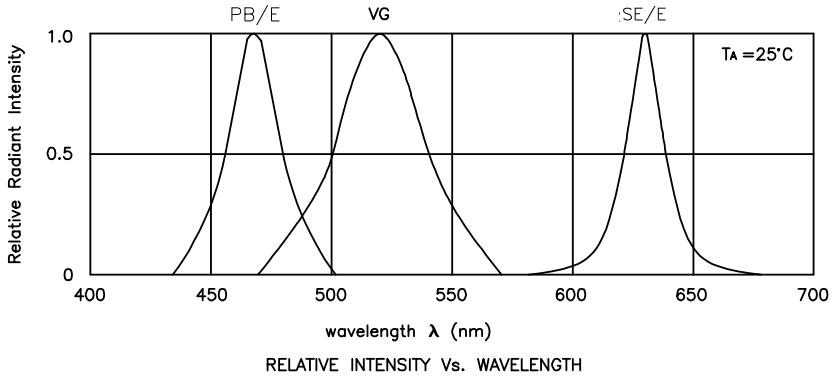
Electrical / Optical Characteristics at T_A=25°C

Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λpeak	Peak Wavelength	Hyper Orange Green Blue	630 520 465		nm	I_F=20mA
λD	Dominant Wavelength	Hyper Orange Green Blue	621 525 470		nm	I_F=20mA
Δλ1/2	Spectral Line Half-width	Hyper Orange Green Blue	20 38 25		nm	I_F=20mA
C	Capacitance	Hyper Orange Green Blue	25 45 110		pF	V_F=0V;f=1MHz
V_F	Forward Voltage	Hyper Orange Green Blue	2.0 3.5 3.7	2.5 4.5 4.3	V	I_F=20mA
I_R	Reverse Current	All		10	uA	V_R = 5V

Absolute Maximum Ratings at T_A=25°C

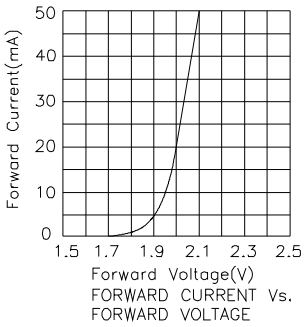
Parameter	Hyper Orange	Green	Blue	Units
Power dissipation [2]	350			mW
DC Forward Current	50	30	30	mA
Peak Forward Current [1]	195	150	160	mA
Reverse Voltage	5	5	5	V
Operating / Storage Temperature	-40°C To +85°C			

Notes:
1. 1/10 Duty Cycle, 0.1ms Pulse Width.
2. Within 350mW at all chips are lightened.

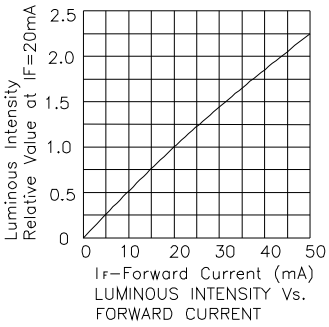


RELATIVE INTENSITY Vs. WAVELENGTH

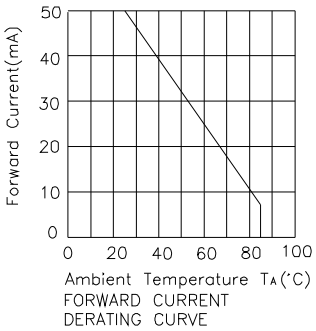
AAA5060SEEVGPBE
Hyper Orange



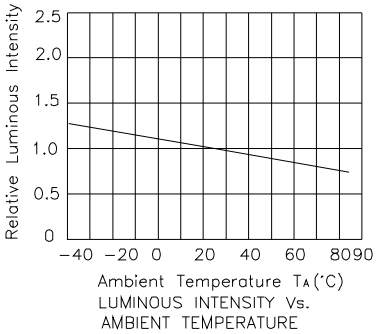
FORWARD CURRENT Vs.
FORWARD VOLTAGE



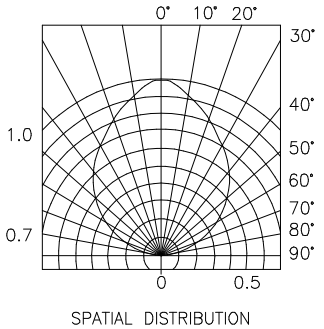
LUMINOUS INTENSITY Vs.
FORWARD CURRENT



FORWARD CURRENT
DERATING CURVE

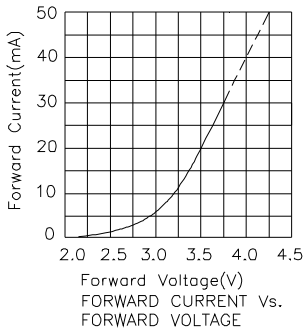


LUMINOUS INTENSITY Vs.
AMBIENT TEMPERATURE

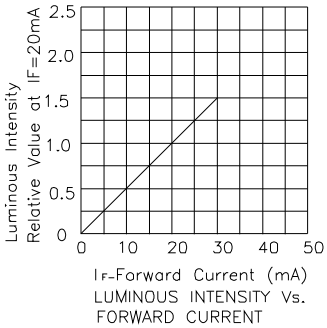


SPATIAL DISTRIBUTION

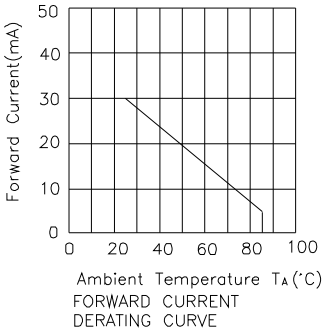
Green



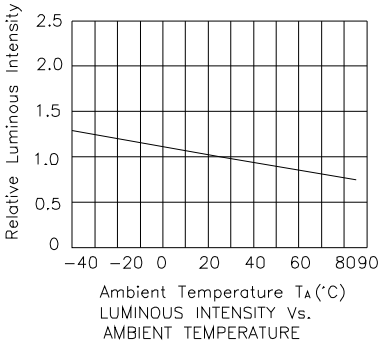
FORWARD CURRENT Vs.
FORWARD VOLTAGE



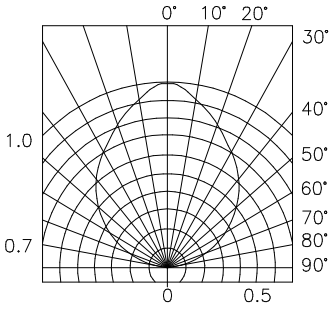
LUMINOUS INTENSITY Vs.
FORWARD CURRENT



FORWARD CURRENT
DERATING CURVE

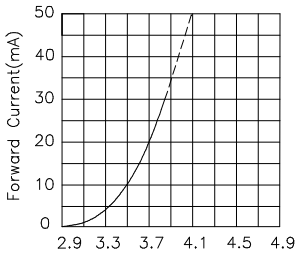


LUMINOUS INTENSITY Vs.
AMBIENT TEMPERATURE

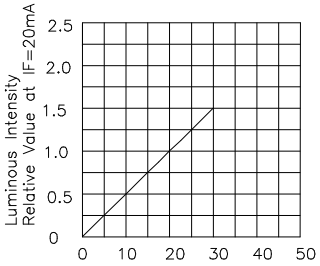


SPATIAL DISTRIBUTION

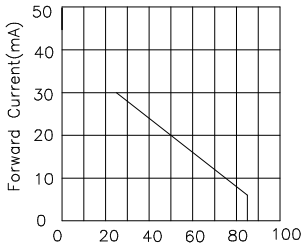
Blue



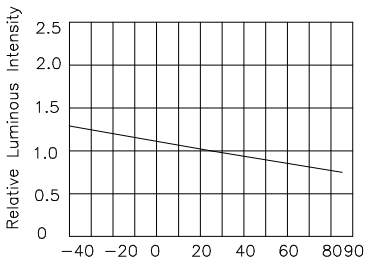
FORWARD CURRENT Vs.
FORWARD VOLTAGE



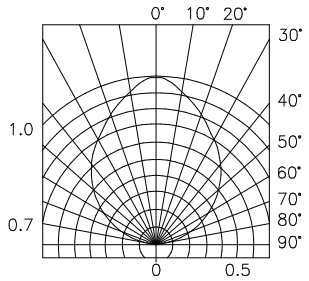
LUMINOUS INTENSITY Vs.
FORWARD CURRENT



FORWARD CURRENT
DERATING CURVE



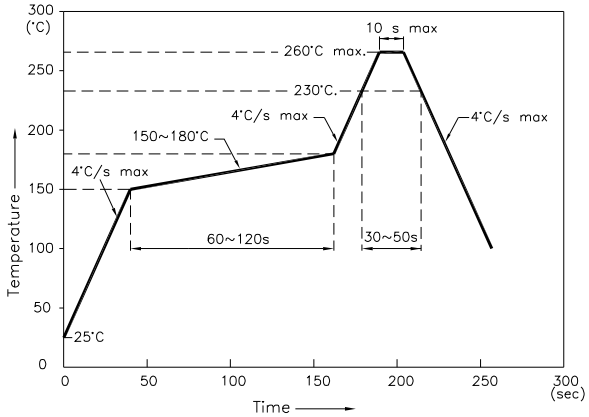
LUMINOUS INTENSITY Vs.
AMBIENT TEMPERATURE



SPATIAL DISTRIBUTION

AAA5060SEEVGPBE

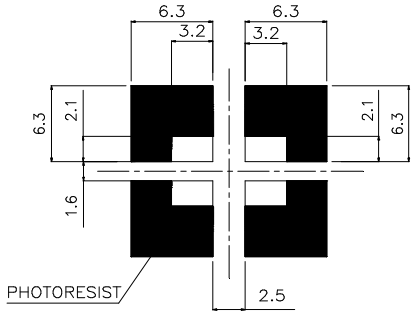
Reflow Soldering Profile For Lead-free SMT Process.



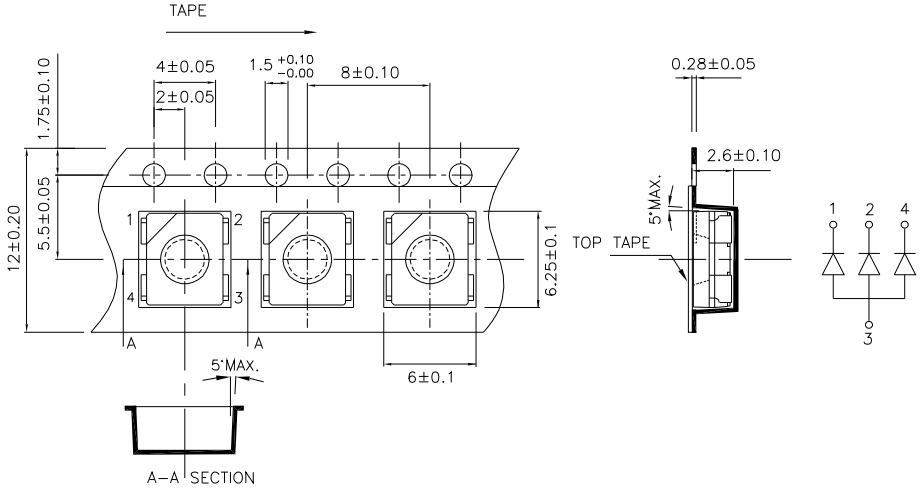
NOTES:

1. We recommend the reflow temperature 245°C(+/-5°C).The maximum soldering temperature should be limited to 260°C.
2. Don't cause stress to the epoxy resin while it is exposed to high temperature.
3. Number of reflow process shall be 2 times or less.

Recommended Soldering Pattern (Units : mm)



Tape Specifications (Units : mm)



Remarks:

If special sorting is required (e.g. binning based on forward voltage, luminous intensity, or wavelength), the typical accuracy of the sorting process is as follows:

1. Wavelength: +/-1nm
2. Luminous Intensity: +/-15%
3. Forward Voltage: +/-0.1V

Note: Accuracy may depend on the sorting parameters.